Low power consumption, Low ESR Cap. Compatible HM6216 Series

General Description
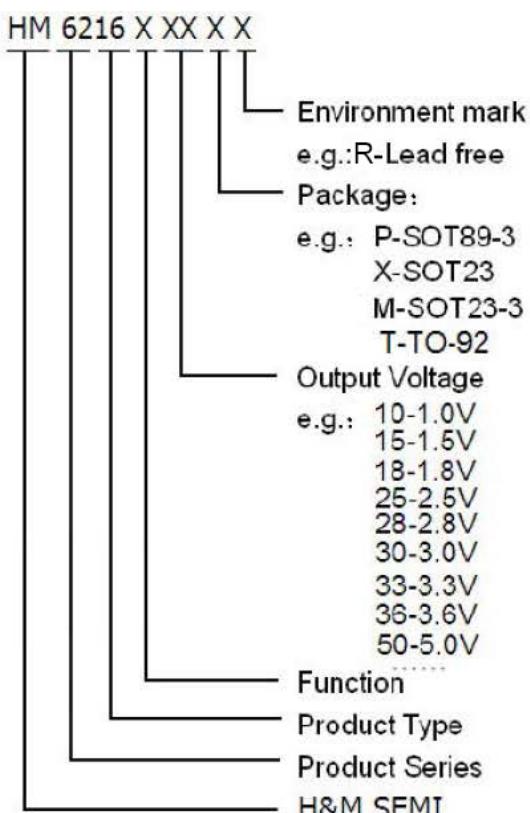
HM6216 series are highly precise, low power consumption, positive voltage regulators manufactured using CMOS technologies .The series provides large currents with a significantly small dropout voltage.

The series is compatible with low ESR ceramic capacitors .The current limiter's foldback circuit also operates as a short protect for the output current limiter and the output pin.

Features

- Highly Accurate：±1%
- Output voltage range：1.0V~5.0V
- Low power consumption：4uA(TYP.)
- Large output current：300mA (V$_{IN}$＝4.3V,V$_{OUT}$＝3.3V)
- Input voltage: up to 6 V
- Dropout voltage：
  0.11V at 100mA and 0.24V at 200mA
- Excellent Input Stability
- Be available to regulator and reference voltage
- Packages:SOT23-3，SOT89-3，SOT23，TO-92

## Selection Guide

HM 6216 X XX X X

Environment mark
e.g.:R-Lead free

Package：
e.g.：P-SOT89-3
X-SOT23
M-SOT23-3
T-TO-92

Output Voltage
e.g.：10-1.0V
15-1.5V
18-1.8V
25-2.5V
28-2.8V
30-3.0V
33-3.3V
36-3.6V
50-5.0V

Function

Product Type

Product Series

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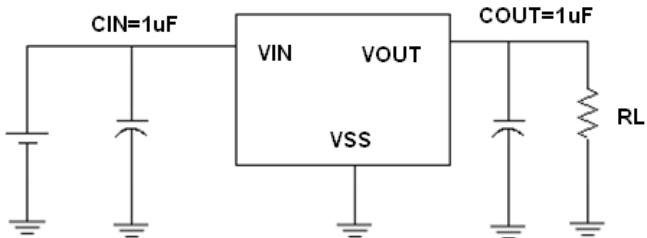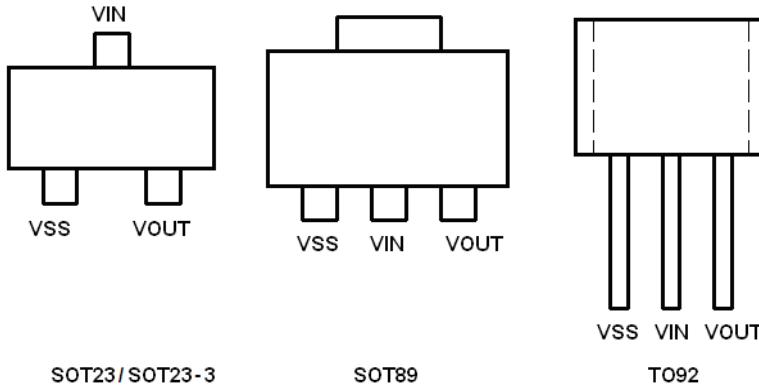
Typical Application

- Battery powered equipment
- Communication tools
- Mobile phones
- Portable games
- Portable AV systems
- Cameras, Video systems
- Reference voltage sources

Typical Application Circuit

Pin Configuration

SOT23/SOT23-3   SOT89   TO92

Pin Assignment

HM6216Axx

Pin				Name	Function
M3	P	X	T		
SOT23-3	SOT89-3	SOT23	TO-92		
1	1	1	1	VSS	Ground
2	3	2	3	VOUT	Output
3	2	3	2	VIN	Input
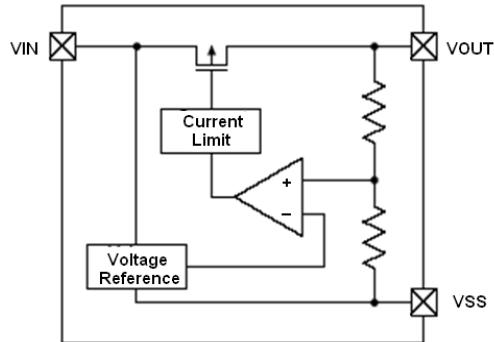
HM6216Bxx

Pin	Name	Function
P		
SOT89-3		
2	VSS	Ground
1	VOUT	Output
3	VIN	Input

Absolute Maximum Ratings

Parameter		Symbol	Description	Units
Input Voltage		V_{IN}	6.5	V
Output Current		I_{OUT}	390	mA
Output Voltage		V_{OUT}	Vss-0.3 ~ Vout+0.3	V
Power Dissipation	SOT23-3	Pd	300	mW
	SOT89-3	Pd	500	mW
	SOT23	Pd	300	mW
	TO-92	Pd	500	mW
Operating Ambient Temperature		T_{Opr}	-25 ~ +85	℃
Storage Temperature		T_{stg}	-40 ~ +125	℃

Block Diagram

Electrical Characteristics

HM6216-3.3V

(V_{IN}=V_{OUT}+1V,CIN=COUT=1uF,Ta=25°C Unless otherwise stated)

| PARAMETER	SYMBOL	CONDITION	MIX	TYP	MAX	UNIT
Output Voltage	V_{OUT}(E) (Note 2)	I_{OUT}=10mA, V_{IN}=V_{OUT}+1V	X 0.99	V_{OUT}(T) (Note 1)	X 1.01	V
Input Voltage	V_{IN}				6	V
Maximum Output Current	I_{OUT} (max)	V_{IN}= V_{OUT} +1V		300	350	mA
Load Regulation	ΔV_{OUT}	V_{IN}= V_{OUT} +1V 1mA≤I_{OUT}≤100mA		9	18	mV
Dropout Voltage (Note 3)	V_{dif1}	I_{OUT} =80mA		100	120	mV
	V_{dif2}	I_{OUT} =200mA		240	260	mV
Supply Current	I_{SS}	V_{IN}= V_{OUT} +1V		4	8	µA
Line Regulations	$\dfrac{\Delta V_{OUT}}{\Delta V_{IN} \cdot V_{OUT}}$	I_{OUT} =40mA Vout+1V ≤V_{IN}≤6V		0.07	0.2	%/V
Power Supply Ripple Rejection Ratio	PSRR	Vin= [V_{OUT} +1]V +1Vp-pAC I_{OUT} =10mA,f=1kHz		50		dB
Short Circuit Current	I short	Vin= V_{OUT} (T)+1V V_{OUT} =VSS		30	60	mA
Over Current Protection	I limit	V_{IN}= V_{OUT} +1V		420	450	mA
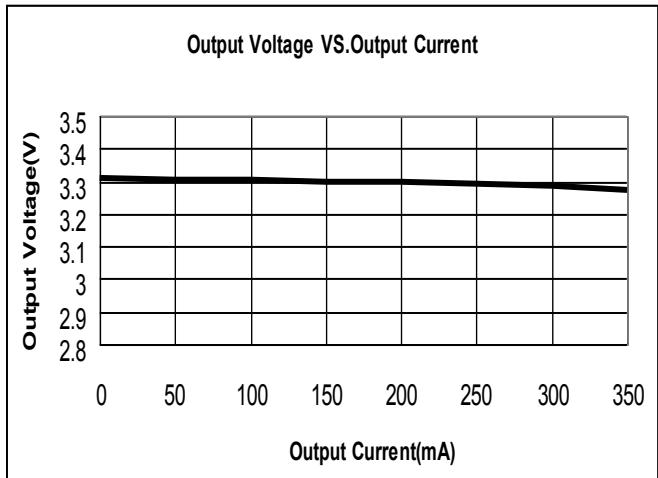
Note :

1. V_{OUT} (T) ：Specified Output Voltage

2. V_{OUT} (E) ：Effective Output Voltage (Ie. The output voltage when "V_{OUT} (T)+1.0V"is provided at the Vin pin while maintaining a certain I_{OUT} value.)

3. V_{dif} ： V_{IN1} −V_{OUT} (E)'

   V_{IN1} ： The input voltage when V_{OUT}(E)' appears as input voltage is gradually decreased.

   V_{OUT} (E)'=A voltage equal to 98% of the output voltage whenever an amply stabilized I_{OUT} {V_{OUT} (T)+1.0V} is input.

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Type Characteristics （HM6216A33）
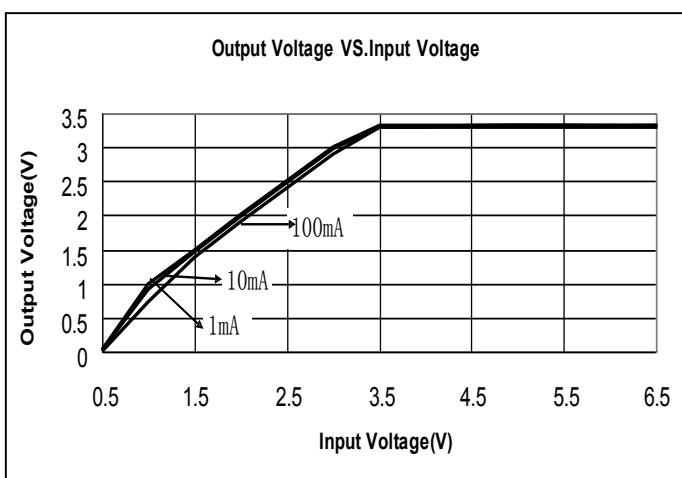
（1）Output Voltage VS. Output Current

（$V_{IN}=V_{OUT}+1$, **Ta = 25 ℃**）

Output Voltage VS.Output Current

（2）Output Voltage VS. Input Voltage
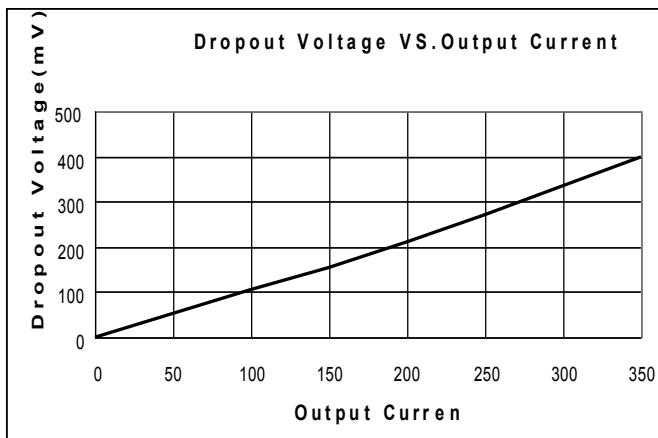
（**Ta = 25 ℃**）

Output Voltage VS.Input Voltage
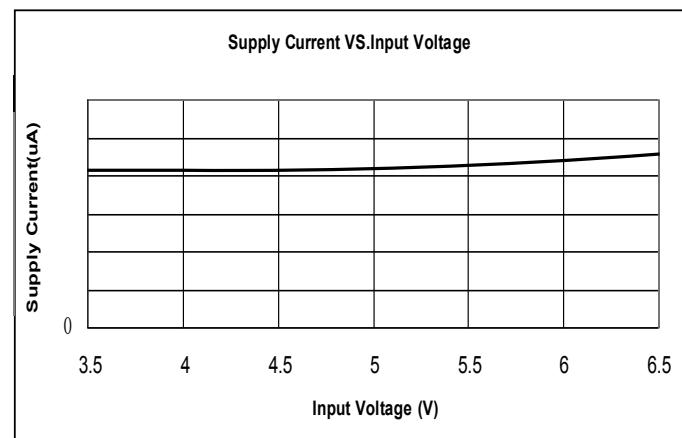
（3）Dropout Voltage VS. Output Current

（$V_{IN}=V_{OUT}+1V$,**Ta = 25 ℃**）

Dropout Voltage VS.Output Current

（4）Supply Current VS. Input Voltage
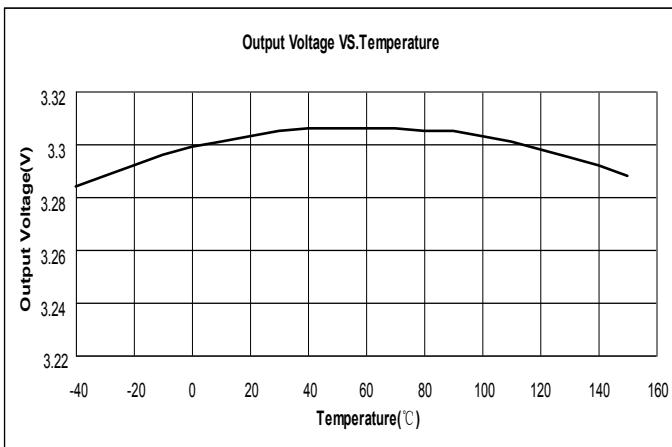
（**Ta = 25 ℃**）

Supply Current VS.Input Voltage
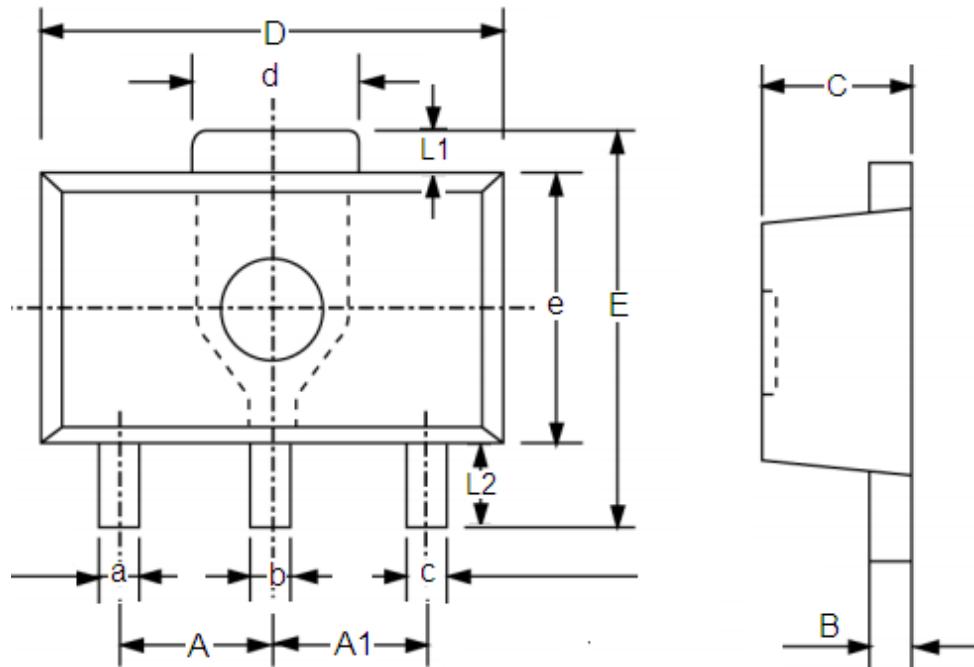
（5）Output Voltage VS. Temperature（$V_{IN}=V_{OUT}+1V$, I_{OUT} =10mA）

Output Voltage VS.Temperature
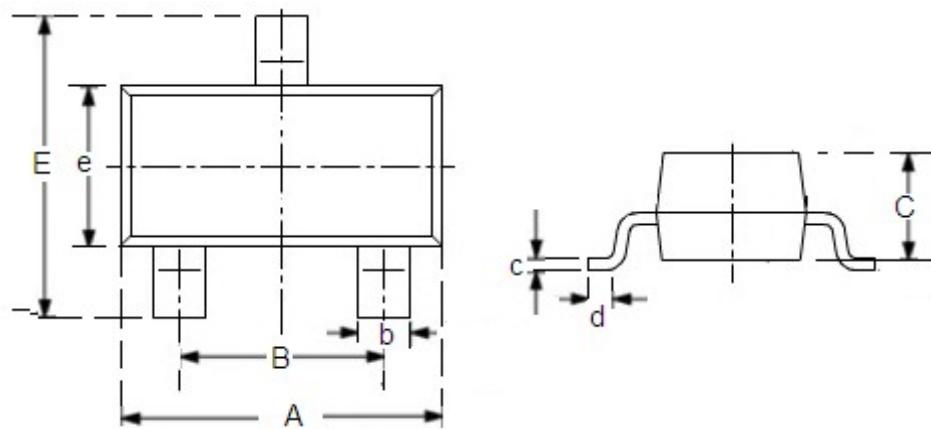
Packaging Information

● SOT89-3
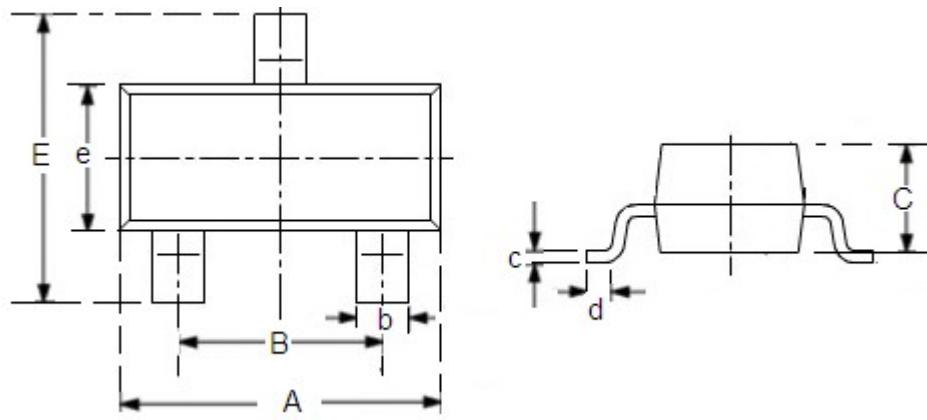
DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	1.4	1.6	0.0551	0.0630
A1	1.4	1.6	0.0551	0.0630
a	0.36	0.48	0.0142	0.0189
b	0.41	0.53	0.0161	0.0209
c	0.36	0.48	0.0142	0.0189
d	1.4	1.75	0.0551	0.0689
B	0.38	0.43	0.015	0.0169
C	1.4	1.6	0.0551	0.0630
D	4.4	4.6	0.1732	0.181
E	-	4.25	-	0.1673
e	2.4	2.6	0.0945	0.1023
L1	0.4	-	0.0157	-
L2	0.8	-	0.0315	-

● SOT23-3
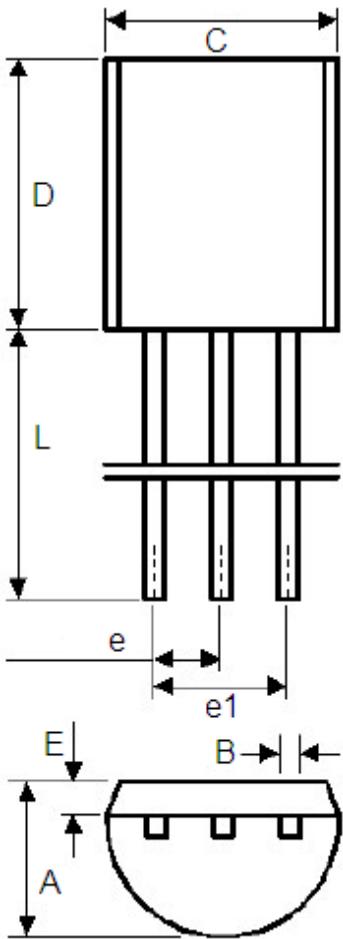
DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	2.7	3.1	0.1063	0.122
B	1.7	2.1	0.0669	0.0827
b	0.35	0.5	0.0138	0.0197
C	1.0	1.2	0.0394	0.0472
c	0.1	0.25	0.0039	0.0098
d	0.2	-	0.0079	-
E	2.6	3.0	0.1023	0.1181
e	1.5	1.8	0.059	0.0708

● SOT23

DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	2.7	3.1	0.1063	0.122
B	1.7	2.1	0.0669	0.0827
b	0.35	0.5	0.0138	0.0197
C	1.0	1.2	0.0394	0.0472
c	0.1	0.25	0.0039	0.0098
d	0.2	-	0.0079	-
E	2.1	2.64	0.0827	0.1039
e	1.2	1.4	0.0472	0.0551

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● TO-92

	Min	Max	Min	Max
A	3.4	3.8	0.13386	0.1496
B	0.3	0.5	0.0118	0.0197
C	4.4	4.8	0.1732	0.189
D	4.4	4.8	0.1732	0.189
E	0.9	1.5	0.0354	0.059
e	1.17	1.37	0.046	0.0539
e1	2.39	2.69	0.094	0.1059
L	12	16	0.4724	0.6299